

Features

- $BV_{CEO} > -45V, -60V \& -80V$
- $I_C = -1A$ High Continuous Collector Current
- $I_{CM} = -2A$ Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage $V_{CE(sat)} < -500mV @ -0.5A$
- Gain Groups 10 and 16
- Complementary NPN types: BCP54, 55 and 56
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

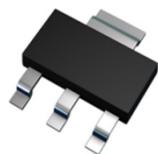
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.112 grams (approximate)

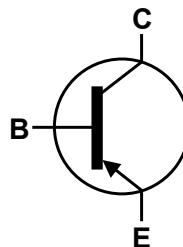
Applications

- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages

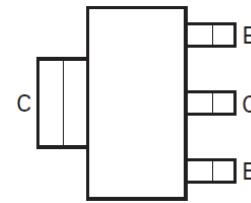
SOT223



Top View



Device Symbol



Top View
Pin-Out

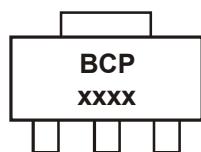
Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BCP51TA	AEC-Q101	BCP 51	7	12	1,000
BCP5110TA	AEC-Q101	BCP 5110	7	12	1,000
BCP5116TA	AEC-Q101	BCP 5116	7	12	1,000
BCP5116TC	AEC-Q101	BCP 5116	13	12	4,000
BCP52TA	AEC-Q101	BCP 52	7	12	1,000
BCP5210TA	AEC-Q101	BCP 5210	7	12	1,000
BCP5216TA	AEC-Q101	BCP 5216	7	12	1,000
BCP53TA	AEC-Q101	BCP 53	7	12	1,000
BCP53QTA	Automotive	BCP 53	7	12	1,000
BCP5310TA	AEC-Q101	BCP 5310	7	12	1,000
BCP5316TA	AEC-Q101	BCP 5316	7	12	1,000
BCP5316TC	AEC-Q101	BCP 5316	13	12	4,000

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>

Marking Information



BCP = Product Type Marking Code, Line 1.

xxxx = Product Type Marking Code, Line 2 as follows:

BCP51 = 51

BCP5110 = 5110

BCP5116 = 5116

BCP52 = 52

BCP5210 = 5210

BCP5216 = 5216

BCP53 = 53

BCP5310 = 5310

BCP5316 = 5316

Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	BCP51	BCP52	BCP53	Unit
Collector-Base Voltage	V_{CBO}	-45	-60	-100	V
Collector-Emitter Voltage	V_{CEO}	-45	-60	-80	V
Emitter-Base Voltage	V_{EBO}		-5		V
Continuous Collector Current	I_C		-1		A
Peak Pulse Collector Current	I_{CM}		-2		
Continuous Base Current	I_B		-100		
Peak Pulse Base Current	I_{BM}		-200		mA

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P_D	2	W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62	°C/W
Thermal Resistance, Junction to Leads	$R_{\theta JL}$	19.4	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +150	°C

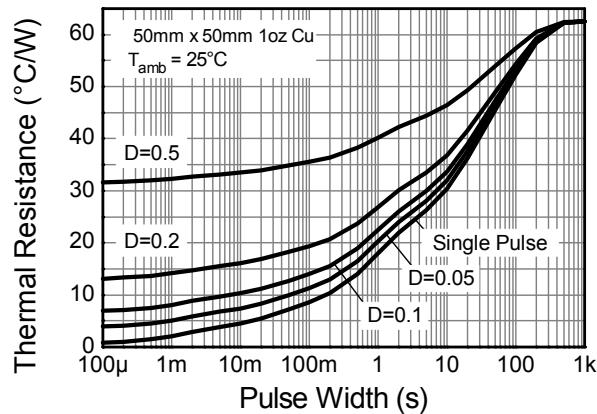
ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

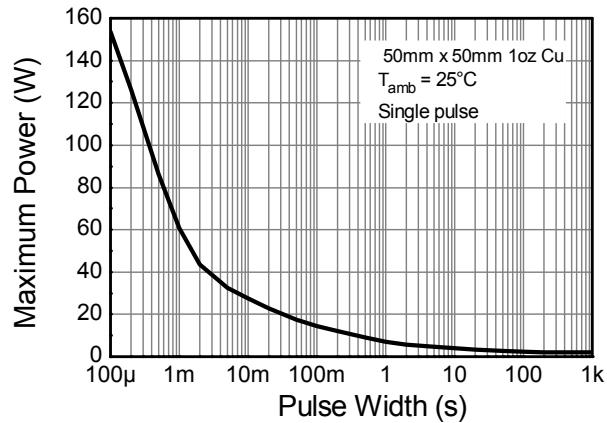
Notes:

- 6. For a device mounted with the collector lead on 50mm x 50mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

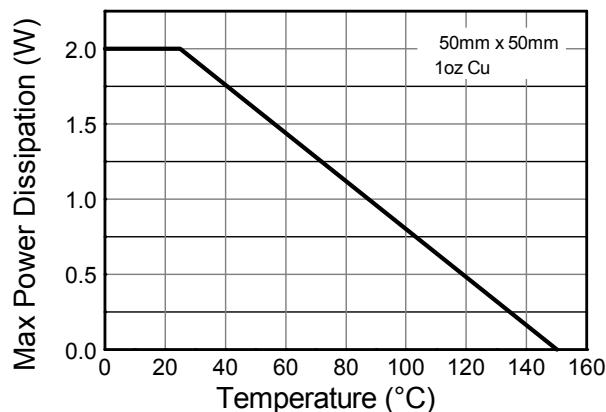
Thermal Characteristics and Derating Information



Transient Thermal Impedance



Pulse Power Dissipation



Derating Curve

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-45	—	—	V	$I_C = -100\mu\text{A}$
		-60				
		-100				
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-45	—	—	V	$I_C = -10\text{mA}$
		-60				
		-80				
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	—	—	V	$I_E = -10\mu\text{A}$
Collector Cut-off Current	I_{CBO}	—	—	-0.1 -20	μA	$V_{CB} = -30\text{V}$ $V_{CB} = -30\text{V}, T_A = +150^\circ\text{C}$
Emitter Cut-off Current	I_{EBO}	—	—	-20	nA	$V_{EB} = -4\text{V}$
Static Forward Current Transfer Ratio (Note 9)	h_{FE}	25	—	—	—	$I_C = -5\text{mA}, V_{CE} = -2\text{V}$
		40	—	250		$I_C = -150\text{mA}, V_{CE} = -2\text{V}$
		25	—	—		$I_C = -500\text{mA}, V_{CE} = -2\text{V}$
		63	—	160		$I_C = -150\text{mA}, V_{CE} = -2\text{V}$
		100	—	250		$I_C = -150\text{mA}, V_{CE} = -2\text{V}$
Collector-Emitter Saturation Voltage (Note 9)	$V_{CE(\text{sat})}$	—	—	-0.5	V	$I_C = -500\text{mA}, I_B = -50\text{mA}$
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(\text{on})}$	—	—	-1.0	V	$I_C = -500\text{mA}, V_{CE} = -2\text{V}$
Transition Frequency	f_T	150	—	—	MHz	$I_C = -50\text{mA}, V_{CE} = -10\text{V}$ $f = 100\text{MHz}$
Output Capacitance	C_{obo}	—	—	25	pF	$V_{CB} = -10\text{V}, f = 1\text{MHz}$

Notes: 9. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

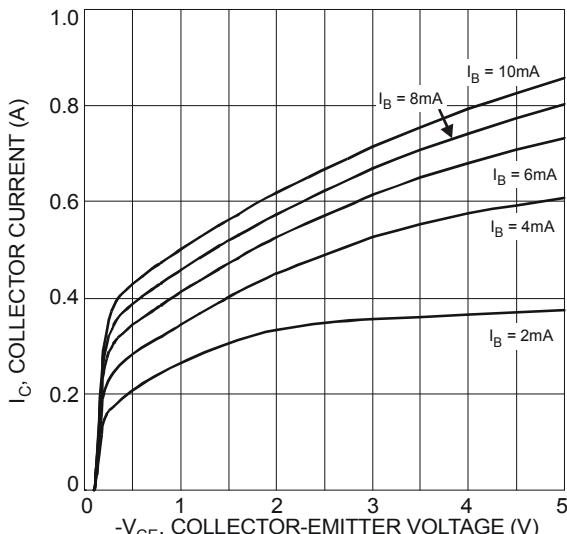


Fig. 1 Typical Collector Current vs. Collector-Emitter Voltage

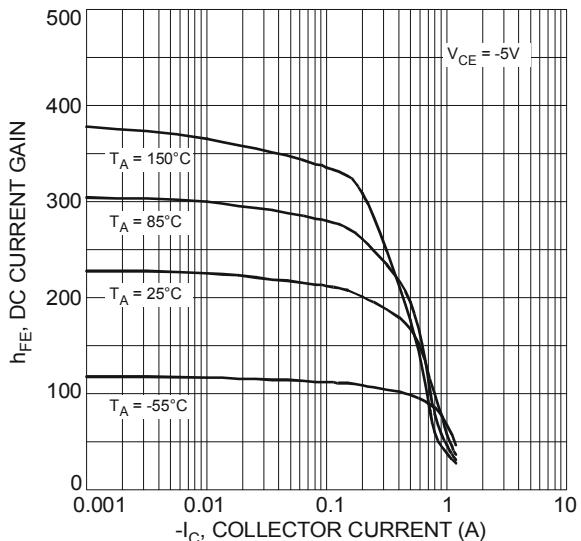


Fig. 2 Typical DC Current Gain vs. Collector Current

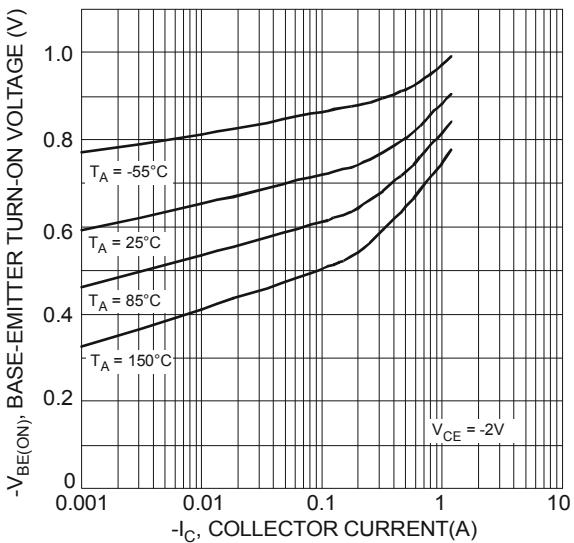


Fig. 3 Typical Base-Emitter Turn-On Voltage vs. Collector Current

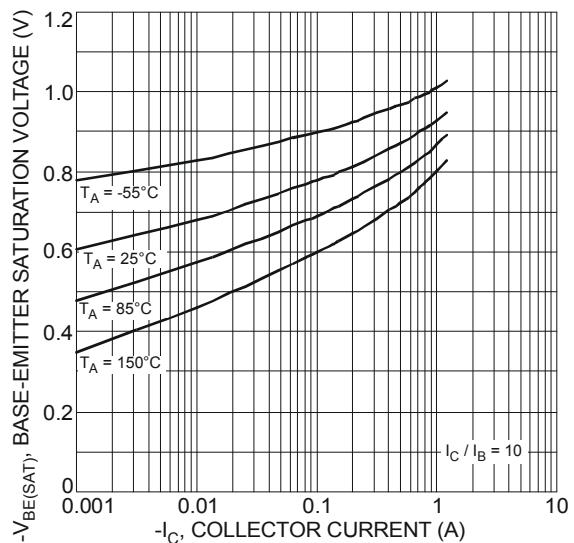


Fig. 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

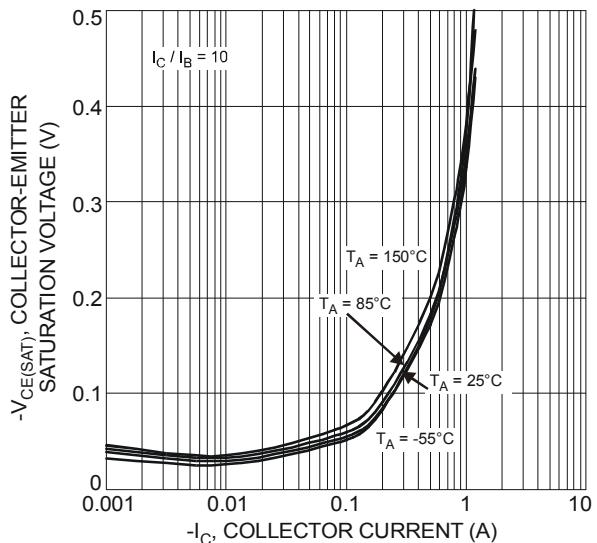


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

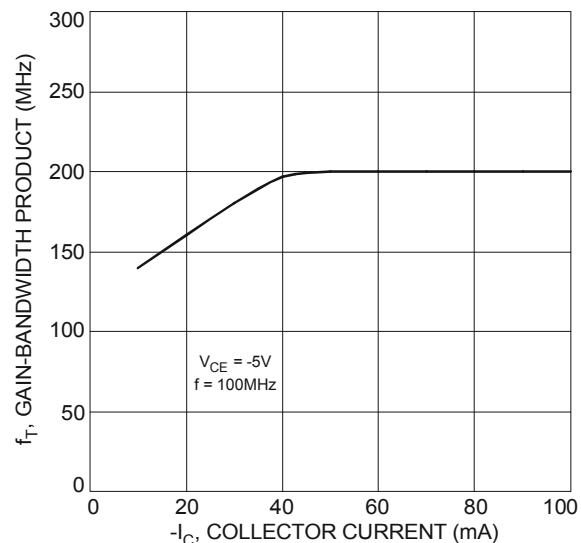


Fig. 6 Typical Gain-Bandwidth Product vs. Collector Current

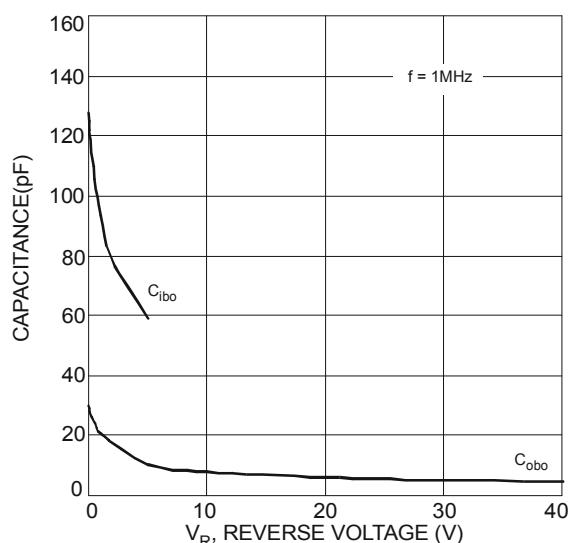
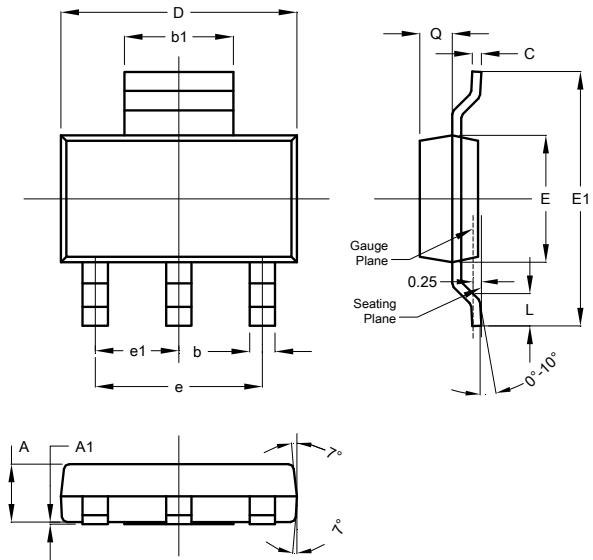


Fig. 7 Typical Capacitance Characteristics

Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

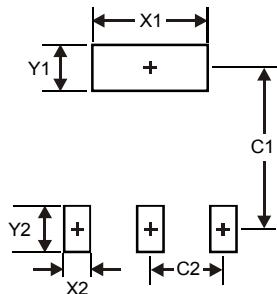


SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89

All Dimensions in mm

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

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